Vishay Semiconductors





www.vishay.com

SMA (DO-214AC)

PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 A				
V _R	200 V				
V _F at I _F	0.75 V				
t _{rr}	25 ns				
T _J max.	175 °C				
Package	SMA (DO-214AC)				
Circuit configuration	Single				

FEATURES

- Hyperfast recovery time, reduced Q_{rr}, and soft recovery
- 175 °C maximum operating junction temperature
- Specified for output and snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in snubber, boost, lighting, piezo injection, as high frequency rectifiers, and freewheeling diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage	V _{RRM}		200	V		
Average rectified forward current	I _{F(AV)}	T _{Sp} = 138 °C	2	^		
Non-repetitive peak surge current	I _{FSM}	$T_J = 25 \text{ °C}, 6 \text{ ms} \text{ square pulse}$	50	A		
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C		

ELECTRICAL SPECIFICATIONS (T _J = 25 $^{\circ}$ C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V_{BR}, V_{R}	I _R = 100 μA	200	-	-	
Forward voltage, per diode	V _F	I _F = 2 A	-	0.88	0.95	V
		I _F = 2 A, T _J = 125 °C	-	0.75	0.82	
Reverse leakage current, per diode	I _R	V _R = V _R rated	-	-	2	μA
neverse leakage current, per diode		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	1	8	μΑ
Junction capacitance	CT	V _R = 200 V	-	8	-	pF

Revision: 20-Sep-17 1 Document Number: 95833 For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>





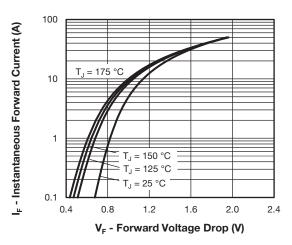


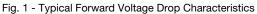
www.vishay.com

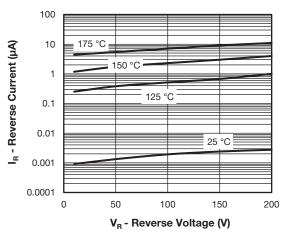
Vishay Semiconductors

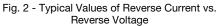
DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 5$	I_F = 1.0 A, d I_F /dt = 50 A/µs, V_R = 30 V		24	-	
Reverse recovery time	t _{rr}	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{rr} = 0.25 \text{ A}$		-	-	25	
		T _J = 25 °C		-	16	-	- ns - A
		T _J = 125 °C	I _F = 2 A, dI _F /dt = 200 A/µs, V _B = 160 V	-	22	-	
Deels receiver a current		T _J = 25 °C		-	2	-	
Peak recovery current	I _{RRM}	T _J = 125 °C		-	3	-	
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	16	-	
		T _J = 125 °C		-	30	-	nC

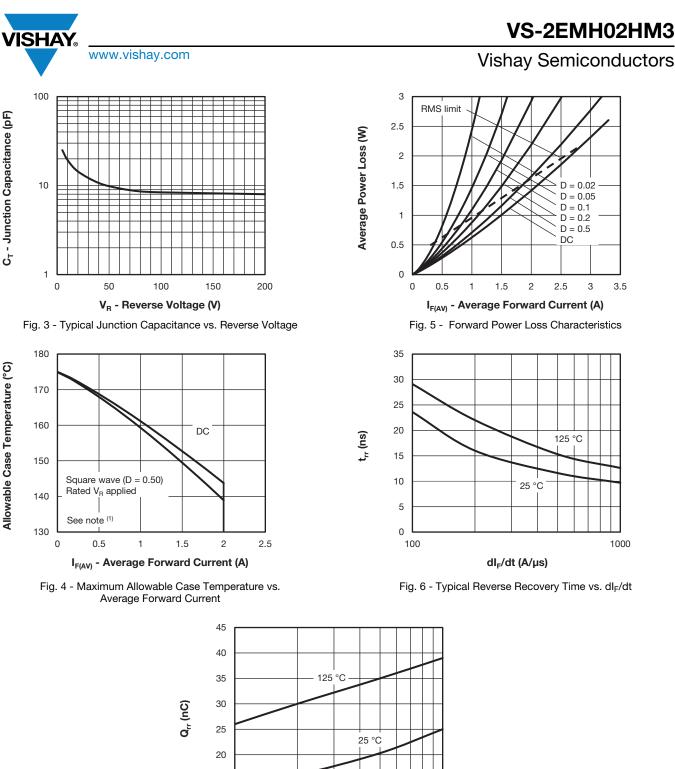
THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C	
Thermal resistance, junction to case	R _{thJC}	Device mounted on PCB with 2 x 3.5 mm soldering lands	-	11	21	°C/W	
Approximate weight				0.07		g	
				0.002		oz.	
Marking device		Case style SMA (DO-214AC)		21	12		











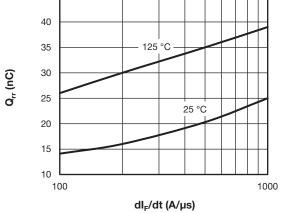


Fig. 7 - Typical Stored Charge vs. dl_F/dt

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{5}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

Revision: 20-Sep-17

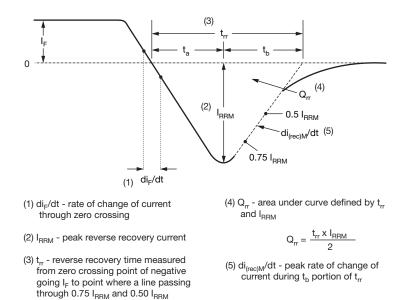
3

Document Number: 95833

For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

VS-2EMH02HM3

Vishay Semiconductors



extrapolated to zero current. Fig. 8 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

www.vishay.com

Device code	VS-	2	Е	м	н	02	н	М3	
		2	3	4	5	6	7	8	1
	1 - 2 -		•	niconduo ng (2 = 1	•	oduct			
	3 -	Circ		iguratio					
	4 - 5 -	- M =	SMA p	ackage					
	6 -	H =	hyperfa	ist recov de (02 =	-				
	7 - 8 -			101 qua en-free,		complia	nt, and	termina	tions lead (Pb)

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-2EMH02HM3/5AT	7500	7500	13"diameter plastic tape and reel				

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95400					
Part marking information	www.vishay.com/doc?95472					
Packaging information	www.vishay.com/doc?95404					
SPICE model	www.vishay.com/doc?96376					

Revision: 20-Sep-17

Document Number: 95833

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



Outline Dimensions

Vishay Semiconductors

SMA

DIMENSIONS in inches (millimeters)

DO-214AC (SMA)





Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Rectifiers category:

Click to view products by Vishay manufacturer:

Other Similar products are found below :

D91A DA24F4100L DD89N1600K-A DD89N16K-K RL252-TP DLA11C-TR-E DSA17G 1N4005-TR BAV199-TP UFS120Je3/TR13 JANS1N6640US VS-80-1293 DD89N16K DD89N16K-A 481235F DSP10G-TR-E RRE02VS6SGTR 067907F MS306 ND104N08K SPA2003-B-D-A01 VS-80-6193 VS-66-9903 VGF0136AB US2JFL-TP UFS105Je3/TR13 A1N5404G-G ACGRA4007-HF ACGRB207-HF RF301B2STL RF501B2STL UES1306 UES1302 BAV199E6433HTMA1 ACGRC307-HF ACEFC304-HF JANTXV1N5660A UES1106 GS2K-LTP D126A45C D251N08B SCHJ22.5K SM100 SCPA2 SCH10000 SDHD5K STTH20P035FP VS-8EWS12S-M3 VS-12FL100S10 ACGRA4001-HF